

12th International "Hiroshima" Symposium on the Development and Application of Semiconductor Tracking Detectors (HSTD12) at Hiroshima, Japan

Tuesday, 17 December 2019

Session9 - Sun: B1F-Meeting rooms#4-6; Mon-Wed: B2F-RAN (14:20 - 16:00)

time	[id] title	presenter
14:20	[221] Test beam studies of barrel and endcap modules for the ATLAS ITk strip detector before and after irradiation	RUEHR, Frederik
14:40	[230] Humidity Sensitivity of Large Area Silicon Sensors: Study and Mitigation	FERNANDEZ-TEJERO, Javier
15:00	[275] Design and performance of strip sensors with slim edges for HPS experiment	FADEYEV, Vitaliy
15:20	[228] First characterisation of 3D pixel sensors irradiated at extreme fluences.	MANNA, Maria PELLEGRINI, Giulio
15:40	[254] Characteristics of silicon strip sensors irradiated up to proton fluence of $10^{17} \text{ n}_{\text{eq}}/\text{cm}^2$	SATO, Katsuya